

SML20EUZ12SC

Enhanced Ultrafast Recovery Diode 1200 Volt, 2 x 20 Amp

Back of Case Cathode SML 20EUZ12SC 1 - Anode 1 2 - Com. Cathode 3 - Anode 2 See package outline for mechanical data and more details

D3 PAK Package

Key Parameters

 V_R (max) 1200V V_F (typ) 3.2V I_F (max) 2 x 20A t_{rr} (max) 40ns

TECHNOLOGY

The planar passivated and enhanced ultrafast recovery diode features a triple charge control action utilising Semelab's Graded Buffer Zone technology combined with low emitter efficiency and local lifetime control techniques.

BENEFITS

- · Very fast recovery for low switching losses
- · Ultra soft recovery with low EMI generation
- High dynamic ruggedness under all conditions
- · Low temperature dependency
- Low on-state losses with positive temperature coefficient
- · Stable blocking voltage and low leakage current
- Avalanche rated for high reliability circuit operation

APPLICATIONS

- Freewheeling Diode for IGBTs and MOSFETs
- Uninterruptible Power Supplies UPS
- Switch Mode Power Supplies SMPS
- · Inverse and Clamping Diode
- Snubber Diode
- Fast Switching Rectification

ABSOLUTE MAXIMUM RATINGS (Tcase = 25°C unless otherwise stated)

V_{RRM}	Peak Repetitive Reverse Voltage	1200V
V_R	DC Reverse Blocking Voltage	1200V
I_{FAV}	Average Forward Current @T _C = 85°C	20A
I _{FSM(surge)}	Repetitive Forward Current	50A
I _{FS(surge)}	Non-Repetitive Forward Current	200A
P_{D}	Power Dissipation @T _C = 85°C	70W
W_{AVL}	Avalanche Energy (L=40mH)	20mJ
T_J , T_{STG}	Operating & Storage Junction Temperature	-55 to 150°C

Semelab PIc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

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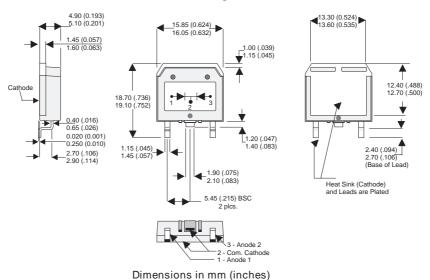


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ELECTRICAL CHARACTERISTICS ($T_{case} = 25^{\circ}C$ unless otherwise stated)

Parameter		Test Conditions		Min.	Тур.	Max.	Unit
STATI	C ELECTRICAL CHARACTERISTI	C					
		I _F = 20A	T _j = 25°C		3.2	3.5	
V _F	Forward Voltage Drop	I _F = 20A	T _j = 125°C			3.7	V
		I _F = 10A	T _j = 25°C		2.5		
I _R	Leakage Current	V _R = 1200V	T _j = 25°C		0.7	500	μΑ
		V _R = 1200V	T _j = 125°C		0.5	4	mA
C _T	Junction Capacitance	V _R = 200V	T _j = 25°C		18		pF
DYNA	MIC ELECTRICAL CHARACTERIS	STIC		•		'	
Q _{rr}	Reverse Recovery Charge	$V_R = 600V$ $d_i / d_t = 1000A/\mu s$	•		0.63		μС
I _{rr}	Reverse Recovery Current				28		А
t _{rr}	Reverse Recovery Time				45		nsec
Q _{rr}	Reverse Recovery Charge	$-V_R = 600V$ $-d_i / d_t = 1000A/\mu s$			0.91		μС
I _{rr}	Reverse Recovery Current				34		А
t _{rr}	Reverse Recovery Time				54		nsec
t _{rr}	Reverse Recovery Time	$V_R = 50V$ $d_i / d_t = 100A/\mu s$	•		40		nsec
THER	MAL AND MECHANICAL CHARAC	CTERISTICS				l .	
$R_{\theta jc}$	Junction to Case Thermal Res	Junction to Case Thermal Resistance				1.4	°C/W
TL	Lead Temperature					300	°C
L _S	Stray Inductance				10		nH

D³PAK Package



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